Detector-Filter Combination Series

Planar Diffused Silicon Photodiodes

The Detector-Filter combination series incorporates a filter with a photodiode to achieve a tailored spectral response. OSI Optoelectronics offers a multitude of standard and custom combinations. Upon request, all detector-filter combinations can be provided with a NIST traceable calibration data specified in terms of Amps/Watt, Amps/lumen, Amps/lux or Amps/ footcandle.

Among many possible custom combinations, following are a few detectorfilter combinations available as standard parts.

PIN-10DF - is a 1 cm2 active area, BNC package detector-filter combination, optimized to achieve a flat responsivity, from 450 to 950 nm. This is the spectral response required for radiometric measurements. This type of detector has several advantages over thermopile, such as sensitivity, which is about a thousand times higher, as well as 10 times more stability.

PIN-10AP-1 - is a 1 cm2 active area, BNC package detector-filter combination which duplicates the response of the most commonly available optical aid; the human eye. The eye senses both brightness and color, with response varying as a function of the wavelength. This response curve is commonly known as the CIE curve. The AP filters accurately match the CIE curve to within 8% of area.



APPLICATIONS

- Analytical Chemistry
- Spectrophotometry
- Densitometers
- Photometry/Radiometry
- Spectroradiometry
- Medical Instrumentation
- Liquid Chromatography

FEATURES

- CIE Match (AP series)
- Flat Band Response (DF)
- 254 Narrow Bandpass
- w/ Amplifier Hybrid
- BNC Packages

PIN-555AP-1 - has the same optical characteristics as the PIN 10-AP-1, with an additional operational amplifier in the same package. The package and the opamp combination is identical to UDT-555D detector-amplifier combination (Photops™).

PIN-005E-550F - uses a low cost broad bandpass filter with peak transmission at 550nm to mimic the CIE curve for photometric applications. The pass band is similar to the CIE curve, but the actual slope of the spectral response curve is quite different. This device can also be used to block the near IR portion of the spectral range, 700 nm and above.

PIN-005D-254F - is a 6 mm² active area, UV enhanced photodiode-filter combination which utilizes a narrow bandpass filter peaking at 254 nm.

CUSTOMIZED CAPABILITIES

Current existing standard photodiodes can be modified by adding various optical filter(s), to match your specific spectral requirements. The filters can either replace the standard glass windows or be used in conjunction with the glass window, depending on the specific requirement and / or nature of the filter. Customer furnished optical filters can also be incorporated in the package. The following are among a few of the optical filter types available. These colored glass filters are grouped into four major categories: Shortpass Filters, Longpass Filters, Bandpass Filters, and Neutral Density Filters. Windows are also available with Custom Thin Film, Anti-reflective, Cut-on and Cut-off Filter Coatings.

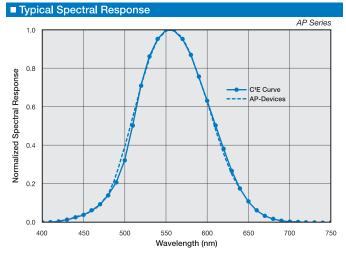
ALL PHOTODIODES WITH OR WITHOUT FILTERS CAN BE CALIBRATED IN HOUSE FOR RESPONSIVITY FROM 200 NM TO 1100 NM IN 10 NM STEPS AS WELL AS SINGLE POINT CALIBRATION, ALL OPTICAL CALIBRATIONS ARE NIST TRACEABLE.

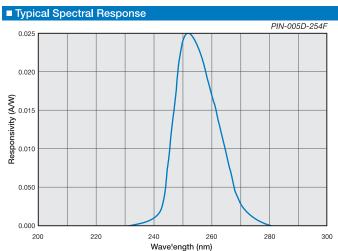
■ Detector-Filter Combination Series

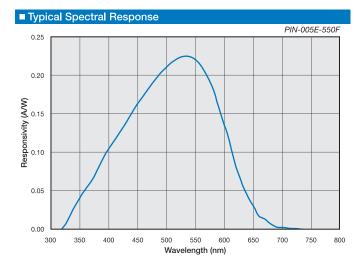
Typical Electro-Optical Specifications at T_A=23°C

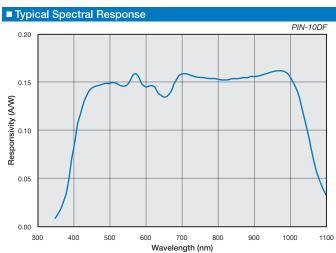
nber	Acti	ve Area	Spectral Match	·	nsivity at Onm	Capacitance (pF)	Shunt Resistance (MΩ)	NEP (W/√Hz)	Rise Time (µs)	Temp. Range (°C)		
Model Number	(mm²)	Dimensions (mm)	λp (nm)	(A/W)	mA/Lum	0 V	-10 mV	-10mV 550 nm	0 V 550 nm 50 Ω	rating	Storage	Package Style ¶
Ψ	Area	Dime (n	typ.	typ.		typ.	typ.	typ.	typ.	Oper	Sto	
Detector Filter Combination Series												
PIN-10DF	100	11.28 ф	± 7% ‡	0.15		1500	20	1.9 e-13	1.0	0 ~ + 70	-85	13 / BNC
PIN-10AP-1			8%***	0.24	0.4			1.1 e-13	0.15			
PIN-555AP-1§			8%	0.24	0.4						5	33 / Special
PIN-005E-550F	5.7	2.4 sq.		0.23		200	500	2.5 e-14	0.1*		-25	5 / TO-5
PIN-005D-254F	5./			0.025*		100	300	3.0 3-13*				18 / TO-5

[‡] Point by point from 450nm to 950nm.









[§] PIN-555AP is a Detector / Operational Amplifier hybrid. For Op-Amp specifications, please see p.29.

[¶] For mechanical drawings please refer to pages 58 thru 69.

* \(\lambda = 254 \text{nm} \)

^{**} Non-condensing temperature and storage range, Non-condensing environment.

^{***} Area within CIE Curve

■ Series E

Eye Response Detectors

Series E photodiodes are Blue-enhanced detectors with high quality color-correcting filters. The resulting spectral response approximates that of the human eye.

In addition to the Series E photodiodes listed, OSI Optoelectronics can provide other photodiodes in this catalog with a variety of optical filters.



APPLICATIONS

- Photometry/Radiometry
- Medical Instrumentation
- Analytical Chemistry

FEATURES

- Human Eye Response
- TO Can Packages

nber	Area (mm²) Dimensions eas		Responsivity nA Lux ⁻¹		Dark Current (nA)		NEP (WHz ^{-1/2})	Capacitance (pF)		Shunt Resistance Megaohms**		Reverse Voltage (DC)	Spectral Curve	Temp. Range (°C)		
Model Number							550 nm VR=0							Operating	Storage	Package Style ¶
Ψ	Area Dime	Dime (n	min.	typ.	max.	typ.	typ.	Vr=0V max.	Vr=12V max.	min.	typ.	max.		Ореі	Sto	
OSD-E Se	OSD-E Series															
OSD1-E	1	1.0 x 1.0	1	2.2	1	0.2	1.5 x 10 ⁻¹⁴	35	7	250	1000		1			7 / TO-18
OSD3-E	3	2.5 x 1.2	3	6.6	2	0.5	1.8 x 10 ⁻¹⁴	80	20	100	700		1	-25 ~ +85	120	7 / TO-18
OSD5-E	5	2.5 dia.	5	11	2	0.5	1.9 x 10 ⁻¹⁴	130	35	100	600	15	1		-40 ~ +	5 / TO-5
OSD15-E	15	3.8 x 3.8	15	33	10	2	5.2 x 10 ⁻¹⁴	390	80	50	80]	1			5 / TO-5
OSD60-E	100	11.3 dia.	30	56	30	8	1.2 x 10 ⁻¹³	2500	520	2	10		2			72 / TO-8

Characteristics measured at 22° C (±2) and a reverse bias of 12 volts unless otherwise stated.

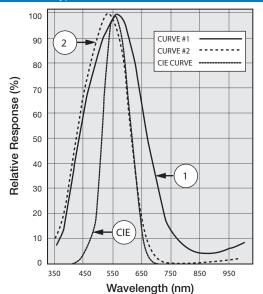
Unit Conversion Table for Illuminance

The Series E photodiodes have been color corrected to provide a phototopic eye response. These devices can be used as low illuminance monitors, i.e. visible light measurement instruments and adjusting brightness of visible display.

Lux lx (lm/m²)	Phot Ph (Im/cm²)	Foot-candle fc (lm/ft²)	Watt per square cm* W/cm²			
1	1.000 x 10 ⁻⁴	9.290 x 10 ⁻²	5.0 x 10 ⁻⁶			
1.000 x 10 ⁴	1	9.290 x 10 ²	9.290 x 10 ⁻²			
1.076 x 10 ¹	1.076 x 10 ⁻³	1	5.0 x 10 ⁻⁵			
2.0 x 10 ⁵	1.0 x 10 ¹	1.9 x 10 ⁴	1			

^{*}Total irradiance (measured value) by the CIE standard light source "A".

■ CIE Curve vs. E Type Parts



Shunt Resistance measured at +/- 10mV.

[¶] For mechanical drawings please refer to pages 58 thru 69.

1. Parameter Definitions:

- A = Distance from top of chip to top of glass.
- a = Photodiode Anode.
- B = Distance from top of glass to bottom of case.
- c = Photodiode Cathode
- (Note: cathode is common to case in metal package products unless otherwise noted).
- W = Window Diameter.
- F.O.V. = Filed of View (see definition below).
- 2. Dimensions are in inches (1 inch = 25.4 mm).
- 3. Pin diameters are 0.018 ± 0.002" unless otherwise specified.
- 4. Tolerances (unless otherwise noted)

General: 0.XX ±0.01"

0.XXX ±0.005"

Chip Centering: ±0.010" Dimension 'A': ±0.015"

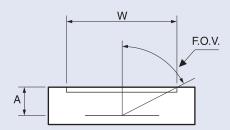
5. Windows

All '**UV**' Enhanced products are provided with QUARTZ glass windows, 0.027 ± 0.002 " thick.

All 'XUV' products are provided with removable windows.

All 'DLS' PSD products are provided with A/R coated glass windows.

All 'FIL' photoconductive and photovoltaic products are epoxy filled instead of glass windows.



$$F.O.V. = \tan^{-1} \left(\frac{W}{2A} \right)$$



For Further Assistance
Please Call One of Our Experienced
Sales and Applications Engineers

310-978-0516



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